

**ZP1000A/600V**

**- Standard Rectifier**

**600 VRRM;**

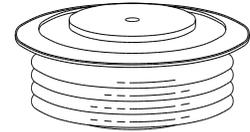
\*\*\*\*\*

**GENERAL PURPOSE HIGH POWER STANDARD RECTIFIER**

**Features:**

- . All Diffused Structure
- . High Surge rating
- . Blocking capability up to 600 volts
- . Soft Reverse Recovery
- . Rugged Ceramic Hermetic Package
- . Pressure Assembled Device

CASE 3D



**ELECTRICAL CHARACTERISTICS AND RATINGS**

**Reverse Blocking**

Device Type	VRRM (1)	VRSM (1)
ZP1000A	600	700

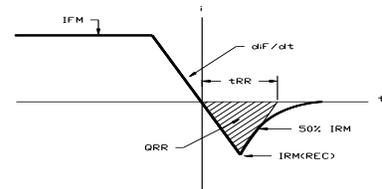
VRRM = Repetitive peak reverse voltage  
 VRSM = Non repetitive peak reverse voltage (2)

Repetitive peak reverse leakage	IRRM	20 mA (3)
---------------------------------	------	-----------

Notes:

All ratings are specified for Tj=25 °C unless otherwise stated.

- (1) All voltage ratings are specified for an applied 50Hz/60Hz sinusoidal waveform over the temperature range -40 to +150 °C.
- (2) 10 msec. max. pulse width
- (3) Maximum value for Tj = 150 °C.
- (4) See parameter definition below :



REVERSE RECOVERY CHARACTERISTIC

**Conducting - on state**

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Average value of on-state current	IF(AV)		1000		A	Sinewave, 180° conduction, Tc = 100°C
RMS value of on-state current	IFRMS		1600		A	Nominal value
Peak one cycle surge (non repetitive) current	IFSM		12000 11000		A A	8.3 msec (60Hz), sinusoidal wave-shape, 180° conduction, Tj = 200 °C 10.0 msec (50Hz), sinusoidal wave-shape, 180° conduction, Tj = 200 °C
I square t	I²t		600000		A²s	10.0 msec
Peak on-state voltage	VFM		1.55		V	IFM = 3000 A; Duty cycle ≤ 0.01%
Reverse Recovery Current (4)	IRM(REC)		*		A	IFM = 1000 A; dIF/dt = 10 A/μs
Reverse Recovery Charge (4)	Qrr		*		μC	
Reverse Recovery Time (4)	tRR		*		μs	

\* For guaranteed maximum values, contact factory

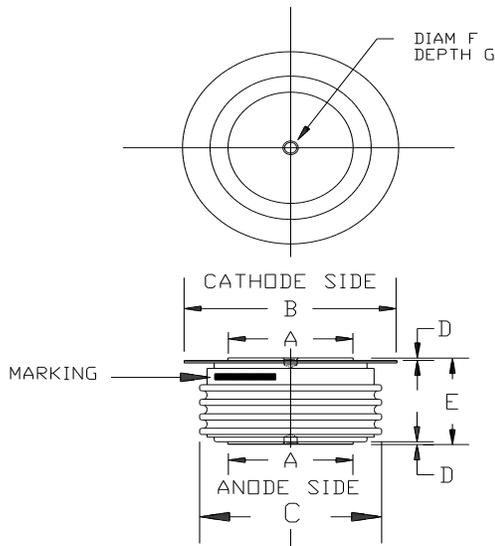
# Technical Data :

## THERMAL AND MECHANICAL CHARACTERISTICS ZP1000A/600V - Standard Rectifier

Parameter	Symb ol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T <sub>j</sub>	-40	+150		°C	
Storage temperature	T <sub>stg</sub>	-40	+150		°C	
Thermal resistance - junction to case	R <sub>θ(j-c)</sub>		0.040 0.080		°C/W	Double sided cooled Single sided cooled
Thermal resistance - case to sink	R <sub>θ(c-s)</sub>		.015 .030		°C/W	Double sided cooled * Single sided cooled *
Mounting force	P	3500 15.5	4500 19.9		lb. kN	
Weight	W			10.8 270	oz. g	

\* Mounting surfaces smooth, flat and greased

### CASE OUTLINE AND DIMENSIONS.



OUTLINE DIMENSIONS - CASE 3D				
DIMENSIONS	Min. mm	Max. mm	Min. In.	Max. In.
DIAM A	33.02	34.29	1.30	1.35
DIAM B	55.88	63.50	2.20	2.50
DIAM C	--	54.61	--	2.15
D	0.76	--	0.03	--
E	25.40	27.18	1.00	1.07
F	3.30	3.81	0.13	0.15
G	1.78	2.03	0.07	0.08

STRIKE DISTANCE = .73 INCH / 18.5 MM MIN.  
CREEPAGE DISTANCE = 1.17 INCH / 29.7 MM MIN.